

Microsemi.

## Power Matters<sup>™</sup>

Home JAN2N1016C (#68500)

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### Products

- Product DirectoryApplications Directory
- ▶ Parametric Search

#### Overview Docs & Specs

# Electrical Rating Symbol Min Typ Max Unit DC Current Gain HFE 10.00 35.00 Drain Current (dc) I<sub>D</sub> 7.50 A Turn Off Time (nS) t<sub>off</sub> 15000.00 ns

Maximum Electrical Rating	Symbol	Min	Тур	Max	Unit
Collector-Emitter Voltage (Base Open)	V <sub>CEO</sub>			100.00	V
Junction Temperature (°C)	$T_J$			150.00	°C

This part can be found in the following product categories:

- Non-Radiation Hardened Devices ▶ Transistors ▶ BJT( BiPolar Junction Transistor) ▶ NPN Transistor
- Discretes ▶ Transistors ▶ BJT( BiPolar Junction Transistor) ▶ NPN Transistor

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